

# SHINDENGEN

## 3 Phase Bridge Diode

## Diode Module

# S10VTA60

## 600V 10A

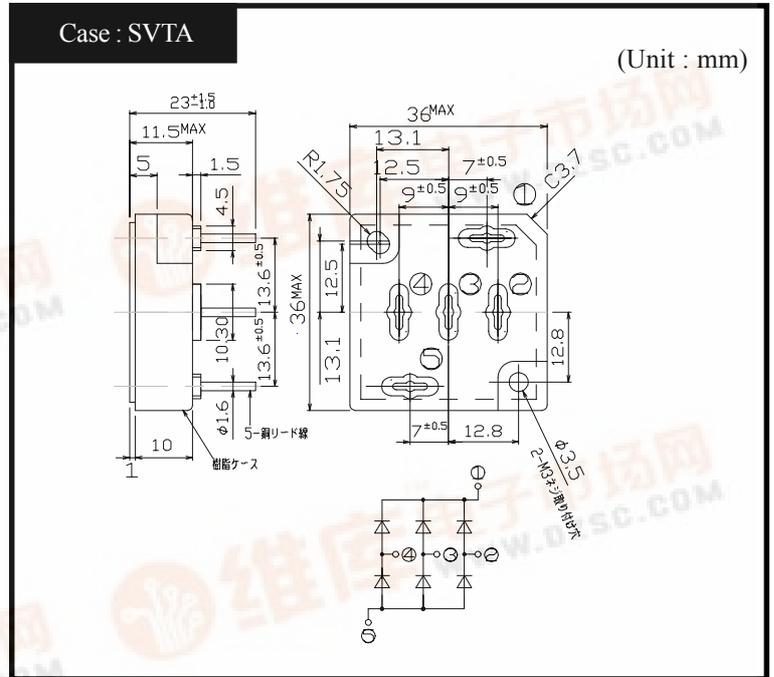
### FEATURES

- Dual In-Line Package
- Compact 3 phase bridge
- High IFSM
- Applicable to mount on glass-epoxy substrate (VTA type)

### APPLICATION

- Big Power Supply
- Air conditioner
- Factory Automation, Inverter

### OUTLINE DIMENSIONS



### RATINGS

- Absolute Maximum Ratings (If not specified Tc=25°C)

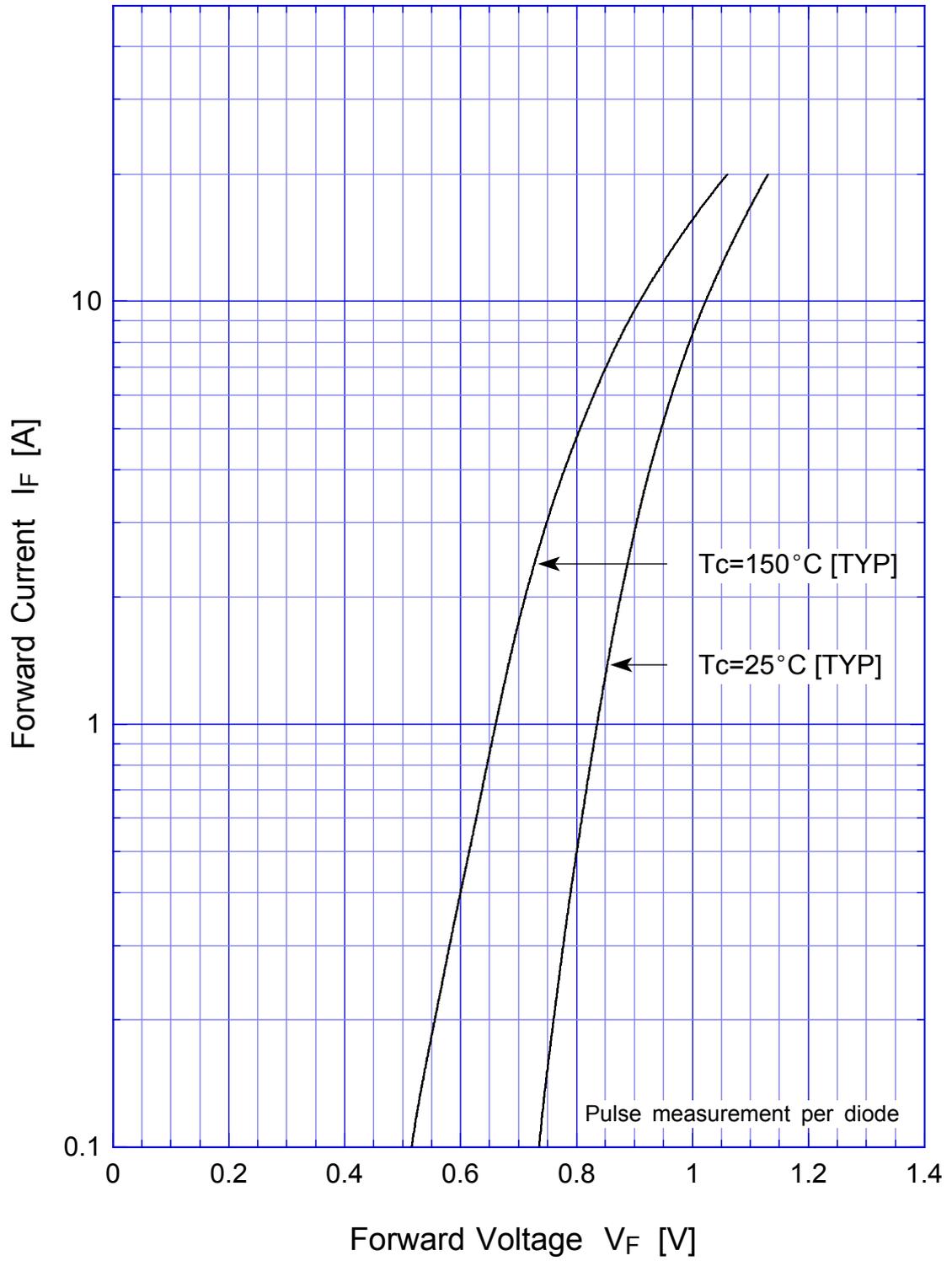
Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	Tstg		-40~150	°C
Operating Junction Temperature	Tj		150	°C
Maximum Reverse Voltage	V <sub>RM</sub>		600	V
Average Rectified Forward Current	I <sub>O</sub>	50Hz sine wave, R-load, With heatsink, Tc=137°C	10	A
Peak Surge Forward Current	I <sub>FSM</sub>	50Hz sine wave, Non-repetitive 1cycle peak value, Rating of per diode, Tj=25°C	170	A
Current Squared Time	I <sup>2</sup> t	2ms ≤ t < 10ms Tc=25°C	140	A <sup>2</sup> s
Dielectric Strength	V <sub>dis</sub>	Terminals to case, AC 1 minute	2	kV
Mounting Torque	TOR	(Recommended torque : 0.6N·m)	0.8	N·m

- Electrical Characteristics (If not specified Tc=25°C)

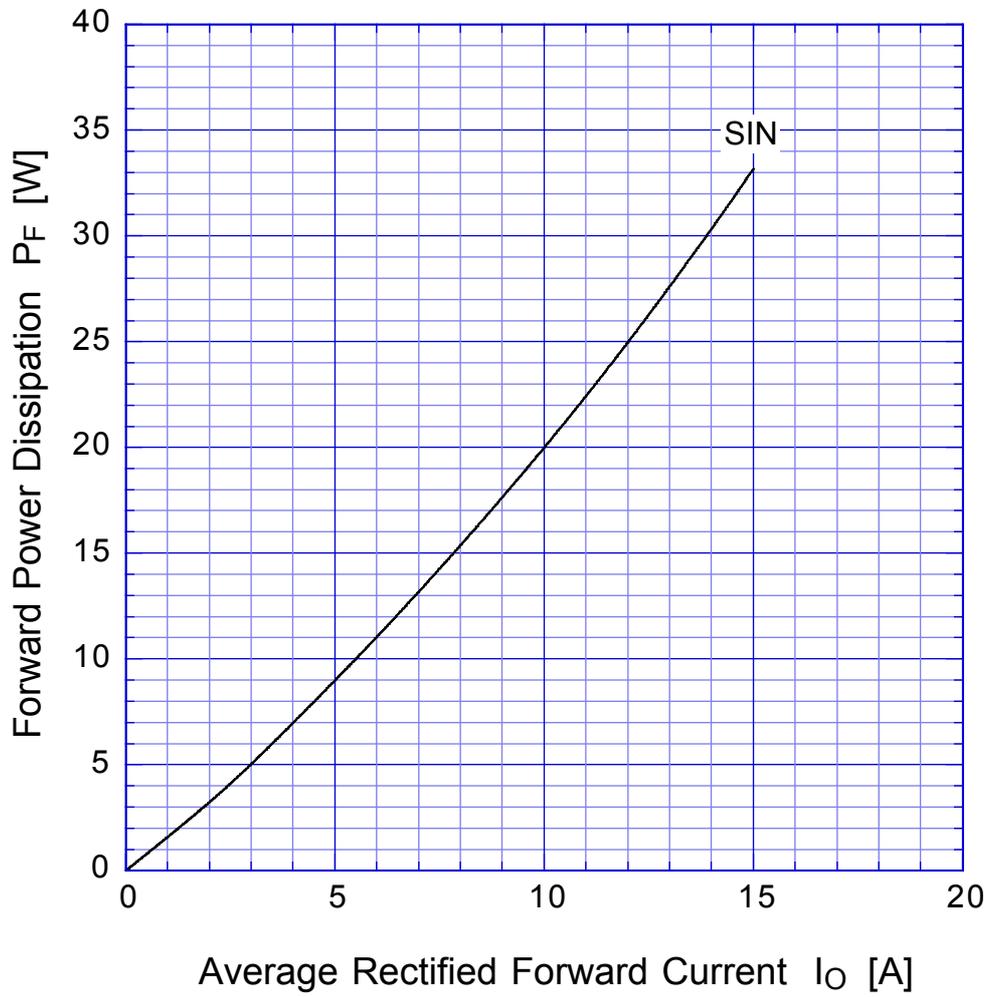
Item	Symbol	Conditions	Ratings	Unit
Forward Voltage	V <sub>F</sub>	I <sub>F</sub> =3.5A, Pulse measurement, Rating of per diode	Max.1.05	V
Reverse Current	I <sub>R</sub>	V <sub>R</sub> =V <sub>RM</sub> , Pulse measurement, Rating of per diode	Max.10	μA
Thermal Resistance	θ <sub>jc</sub>	junction to case	Max.0.65	°C/W



# S10VTA60 Forward Voltage



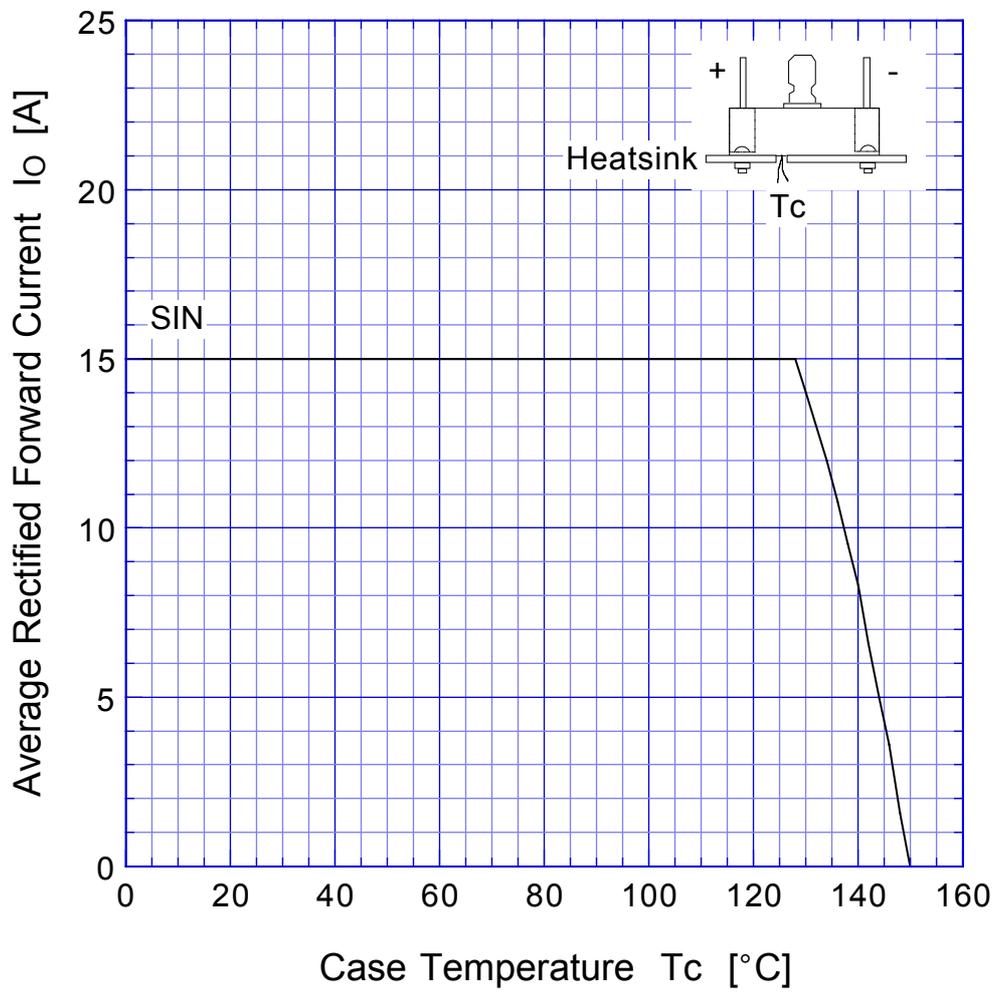
## S10VTA60 Forward Power Dissipation



$T_j = 150^\circ\text{C}$   
Sine wave

# S10VTA60

## Derating Curve



$V_R = V_{RM}$   
Sine wave  
R-load  
with heatsink

# S10VTA60 Peak Surge Forward Capability

